TOSHIBA Photocoupler GaAlAs IRED + Photo IC

TLP351

Inverter for Air Conditioner
IGBT/Power MOS FET Gate Drive
Industrial Inverter

The TOSHIBA TLP351 consists of a GaAlAs light emitting diode and a integrated photodetector.

This unit is 8-lead DIP package.

TLP351 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP351 is capable of "direct" gate drive of lower Power IGBTs.

- Peak output current: ±0.6 A (max)
- Guaranteed performance over temperature: -40 to 100°C
- Supply current: 2 mA (max)
- Power supply voltage: 10 to 30 V
- Threshold input current : $I_F = 5 \text{ mA (max)}$
- Switching time (t_{pLH}/t_{pHL}): 700 ns (max)
- Common mode transient immunity: ±10 kV/μs
- Isolation voltage: 3750 Vrms
- UL approved: UL1577, File No.E67349
- cUL approved :CSA Component Acceptance Service No. 5A, File No.E67349
- Option(D4)

VDE Approved: DIN EN60747-5-5

 $\label{eq:maximum operating Insulation Voltage : 890 V_{PK}} \\ \mbox{Highest Permissible Over Voltage} : 4000 V_{PK} \\ \mbox{: 4000 V_{PK}} \\ \mbox{: 4000 $V_{PK}$$

(Note): When a EN60747-5-5 approved type is needed, Please designate "Option(D4)"

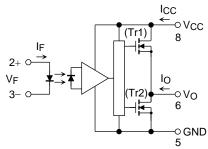
Unit: mm 8 7 6 5 9.66±0.25 1 2 3 4 9.66±0.25 1.2±0.15 0.5±0.1 2.54±0.25 1.7.85~8.80 TOSHIBA 11-10C4

Weight: 0.54 g (typ.)

Truth Table

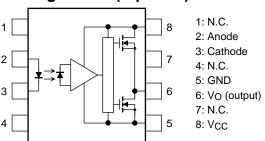
| Input | LED | Tr1 | Tr2 | Output |
|-------|-----|-----|-----|--------|
| Н | ON | ON | OFF | Н |
| L | OFF | OFF | ON | L |

Schematic



A 0.1 μ F bypass capacitor must be connected between pin 8 and 5.

Pin Configuration (top view)



Start of commercial production 2002-05

Absolute Maximum Ratings (Ta = 25°C)

| | Characteristics | Symbol | Rating | Unit | |
|-----------------------------|---|----------|---------------------|------------|-------|
| | Forward current | lF | 20 | mA | |
| | Forward current derating (Ta ≥ 85°C) | | ΔΙϝ/ΔΤα | -0.54 | mA/°C |
| | Peak transient forward current | (Note 1) | IFP | 1 | Α |
| ED. | Reverse voltage | | VR | 5 | V |
| | Power Dissipation | | PD | 40 | mW |
| | Power Dissipation Derating (Ta ≥ 85°C) | | ΔP _D /°C | -1.0 | mW/°C |
| | Junction temperature | | Tj | 125 | °C |
| | "H" peak output current | | Іорн | -0.6 | Α |
| | "L" peak output current | (Note 2) | IOPL | 0.6 | Α |
| or | Output voltage | | Vo | 35 | V |
| Detector | Supply voltage | | Vcc | 35 | V |
| ă | Output Power Dissipation | | Ро | 260 | mW |
| | Output Power Dissipation Derating (Ta ≥ 8 | 35°C) | ΔPo /°C | -6.5 | mW/°C |
| | Junction temperature | | Tj | 125 | °C |
| Oper | ating frequency | (Note 3) | f | 25 | kHz |
| Storage temperature range | | | T _{stg} | −55 to 125 | °C |
| Operating temperature range | | Topr | -40 to 100 | °C | |
| Lead | soldering temperature (10 s) | (Note 4) | T _{sol} | 260 | °C |
| Isola | tion voltage (AC, 1 minute, R.H. ≤ 60%) | (Note 5) | BVs | 3750 | Vrms |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width PW \leq 1 μ s, 300 pps

Note 2: Exponential waveform pulse width PW \leq 10 μ s, f \leq 15 kHz

Note 3: Exponential waveform IOPH ≤ -0.4 A (≤ 2.0 μ s), IOPL $\leq +0.4$ A (≤ 2.0 μ s), Ta = 100°C

Note 4: It is 2 mm or more from a lead root.

Note 5: Device considered a two terminal device: pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Recommended Operating Conditions

| Characteristics | | Symbol | Min | Тур. | Max | Unit |
|-----------------------|----------|-----------|-----|------|------|------|
| Input current, ON | (Note 7) | IF (ON) | 7.5 | _ | 10 | mA |
| Input voltage, OFF | | VF (OFF) | 0 | _ | 0.8 | V |
| Supply voltage | | Vcc | 10 | _ | 30 | V |
| Peak output current | | IOPH/IOPL | _ | _ | ±0.2 | Α |
| Operating temperature | | Topr | -40 | _ | 100 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 7: Input signal rise time (fall time) $< 0.5 \mu s$

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Electrical Characteristics (Ta = -40 to 100°C, unless otherwise specified)

| Characteristics | | Symbol | Test Circuit | Test C | ondition | Min | Typ.* | Max | Unit |
|--|-----------|----------------------|-----------------|---|--|-----|-------|------|-------|
| Forward voltage | | VF | _ | I _F = 5 mA, Ta = 25°C | | _ | 1.55 | 1.70 | V |
| Temperature coefficient of forward voltage | | ΔV _F /ΔTa | _ | I _F = 5 mA | | _ | -2.0 | _ | mV/°C |
| Input reverse current | | I _R | _ | V _R = 5 V, Ta = 25°C | | _ | _ | 10 | μА |
| Input capacitance | | Ст | _ | V = 0 V, $f = 1 MH$ | z,Ta = 25°C | _ | 45 | _ | pF |
| | "H" Level | IOPH1 | 1 | V _{CC} = 15 V | V ₈₋₆ = 4 V | _ | -0.4 | -0.2 | |
| Output current (Note 8) | n Levei | IOPH2 |] ' | I= E m A | V ₈₋₆ = 10 V | _ | -0.67 | -0.4 | |
| | "L" Level | I _{OPL1} | 2 | V _C C = 15 V I _F = 0 mA | V ₆₋₅ = 2 V | 0.2 | 0.35 | _ | Α |
| | | I _{OPL2} | | | V ₆₋₅ = 10 V | 0.4 | 0.63 | _ | |
| | "H" Level | Voн | 3 | V _{CC} = 10 V | $I_O = -100 \text{ mA},$ $I_F = 5 \text{ mA}$ | 6.0 | 8.5 | _ | - V |
| Output voltage | "L" Level | VoL | 4 | | I _O = 100 mA, V _F = 0.8 V | _ | 0.4 | 1.0 | |
| Commission | "H" Level | Іссн | 5 | V _{CC} = 10 to 30 V V _O open | IF = 10 mA | _ | 1.4 | 2.0 | |
| Supply current | "L" Level | ICCL | 6 | | I _F = 0 mA | _ | 1.3 | 2.0 | mA |
| Threshold input current | L → H | I _{FLH} | _ | V _{CC} = 15 V, V _O > 1 V | | _ | 2.5 | 5 | mA |
| Threshold input voltage | H → L | V _{FHL} | _ | V _{CC} = 15 V, V _O < 1 V | | 0.8 | _ | _ | V |
| Supply voltage | | Vcc | _ | _ | | 10 | _ | 30 | V |

^{*:} All typical values are at Ta = 25°C

Note 8: Duration of IO time \leq 50 μ s

Note 9: This product is more sensitive than the conventional product to static electricity (ESD) because of a lowest power consumption design.

General precaution to static electricity (ESD) is necessary for handling this component.

Isolation Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Conditions | Min | Тур. | Max | Unit |
|-----------------------------|--------|---|----------------------|------------------|-----|------------------|
| Capacitance input to output | Cs | $V_S = 0V, f = 1MHz$ (Note5) | | 1.0 | _ | pF |
| Isolation resistance | Rs | V _S = 500 V, R.H. ≤ 60% (Note5 |) 1×10 ¹² | 10 ¹⁴ | _ | Ω |
| | BVS | AC,1 minute | 3750 | _ | _ | V |
| Isolation voltage | | AC,1 second, in oil | _ | 10000 | _ | V _{rms} |
| | | DC,1 minute, in oil | _ | 10000 | - | Vdc |

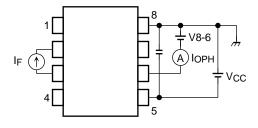
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Switching Characteristics (Ta = -40 to 100° C, unless otherwise specified)

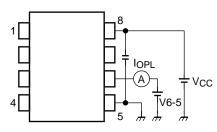
| Characteristics | | Symbol | Test Circuit | Test Co | Test Condition | | Тур.* | Max | Unit |
|---|-------|--|-----------------|--|---|--------|-------|-----|------|
| | L → H | t _{pLH} | | $R_g = 47 \Omega$ | $I_F = 0 \rightarrow 5 \text{ mA}$ | 100 | ı | 700 | |
| Propagation delay time | H → L | t _{pHL} | | | $I_F = 5 \rightarrow 0 \text{ mA}$ | 100 | ı | 700 | ns |
| Propagation delay difference between any two parts or channels | | PDD t _{pHL} -t _{pLH} | 7 | $VCC = 30 \text{ V},$ $R_g = 47 \Omega$ $C_g = 3 \text{ nF}$ | | -500 | 1 | 500 | ns |
| Output rise time (10-90%) | | t _r | | VCC = 30 V | $I_F = 0 \rightarrow 5 \text{ mA}$ | | 50 | - | |
| Output fall time (90-10%) | | t _f | | $R_g = 47 \Omega$ $C_g = 3 nF$ | $I_F = 5 \rightarrow 0 \text{ mA}$ | - | 50 | _ | ns |
| Common mode transient immunity at high level output Common mode transient immunity at low level output | | СМН | - 8 | V _{CM} = 1000 Vp-p | $I_F = 5 \text{ mA}$ $V_{O \text{ (min)}} = 26 \text{ V}$ | -10000 | ı | ı | \//c |
| | | CML | | Ta = 25°C V _{CC} = 30 V | I _F = 0 mA V _{O (max)} = 1 V | 10000 | _ | _ | V/μs |

^{*:} All typical values are at Ta = 25°C

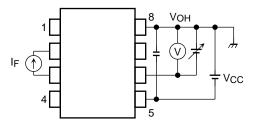
Test Circuit 1: IOPH



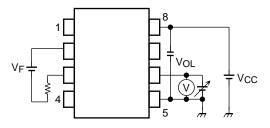
Test Circuit 2: IOPL



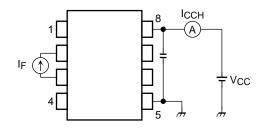
Test Circuit 3: Voн



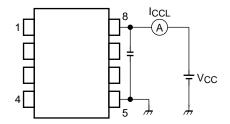
Test Circuit 4: Vol



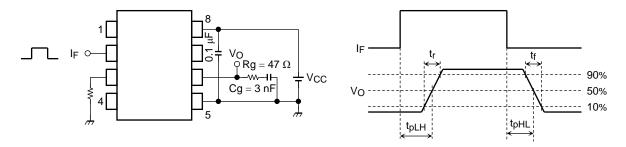
Test Circuit 5: ICCH



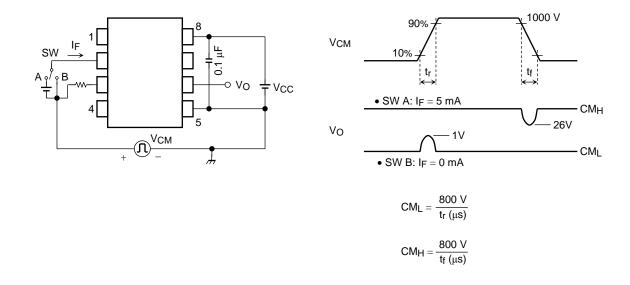
Test Circuit 6: ICCL



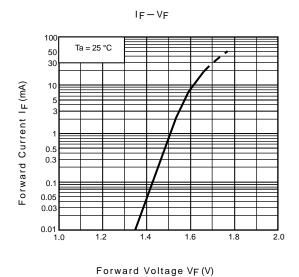
Test Circuit 7: tpLH, tpHL, tr, tf, PDD

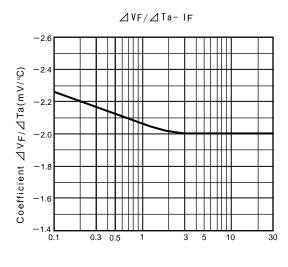


Test Circuit 8: CMH, CML

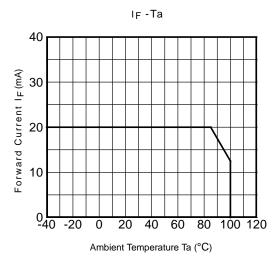


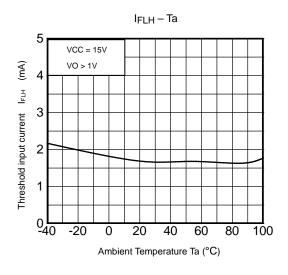
 $\mathrm{CM_L}\left(\mathrm{CM_H}\right)$ is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

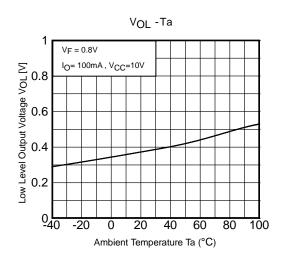


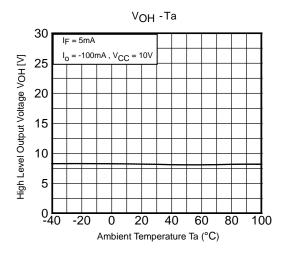


Forward Current I_F (mA)





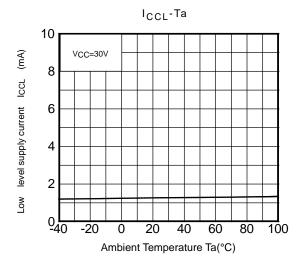


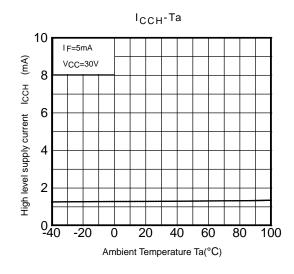


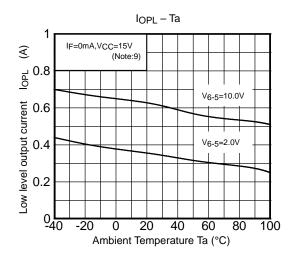
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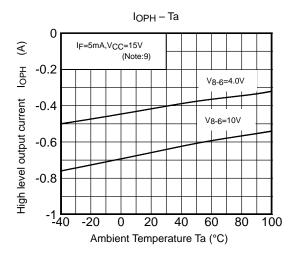
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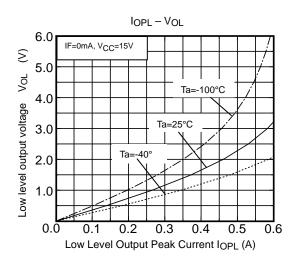
^{*:} The above graphs show typical characteristics.

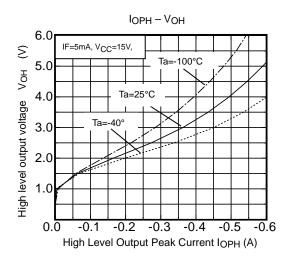




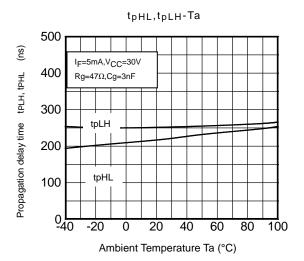








^{*:} The above graphs show typical characteristics.



 $[\]ast \vdots$ The above graphs show typical characteristics.

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